

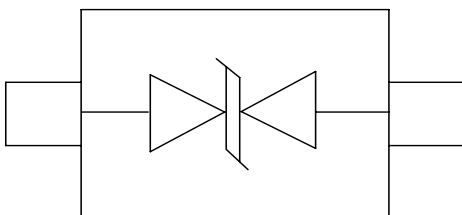
## Description

The PESD5V0S is a bi-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power line. The PESD5V0S complies with the IEC 61000-4-2 (ESD) with  $\pm 30$  kV air and  $\pm 30$  kV contact discharge. It is assembled into an ultra-small SOD-323 lead-free package. The small size and high ESD surge protection make PESD5V0S an ideal choice to protect cell phone, digital cameras, audio players and many other portable applications.

## Features

- Protects one data or power line
- Ultra low leakage: nA level
- Operating voltage: 5V
- Low clamping voltage
- Complies with following standards:
  - IEC 61000-4-2 (ESD) immunity test
    - Air discharge:  $\pm 30$  kV
    - Contact discharge:  $\pm 30$  kV
  - IEC61000-4-5 (Lightning) 8A (8/20 $\mu$ s)
- RoHS Compliant

## Dimensions and Pin Configuration



Circuit and Pin Schematic

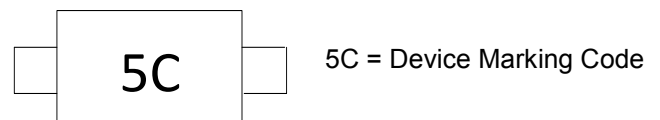
## Mechanical Characteristics

- Package: SOD-323
- Lead Finish: Matte Tin
- Case Material: "Green" Molding Compound.
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminal Connections: See Diagram Below
- Marking Information: See Below

## Applications

- Cellular Handsets and Accessories
- Personal Digital Assistants
- Notebooks and Handhelds
- Portable Instrumentation
- Digital Cameras
- Peripherals
- Audio Players
- Keypads, Side Keys, LCD Displays

## Marking Information



## Ordering Information

Part Number	Packaging	Reel Size
PESD5V0S	3000/Tape & Reel	7 inch

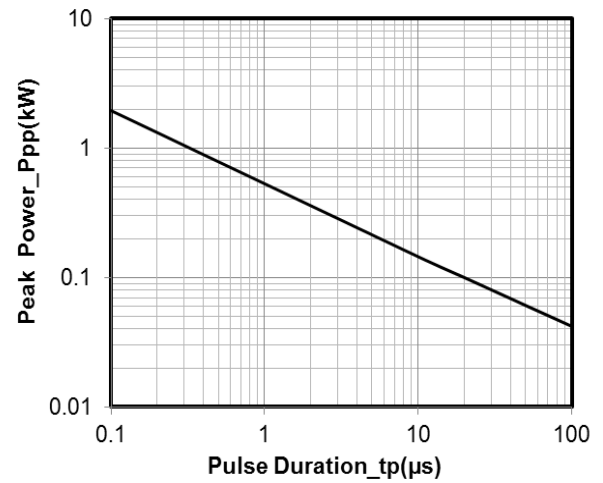
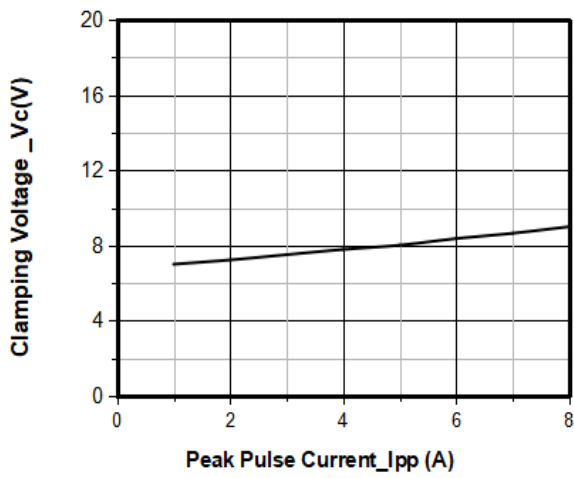
**Absolute Maximum Ratings (T<sub>A</sub>=25°C unless otherwise specified)**

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20μs)	Ppk	100	W
Peak Pulse Current (8/20μs)	I <sub>PP</sub>	8	A
ESD per IEC 61000-4-2 (Air)	V <sub>ESD</sub>	±30	kV
ESD per IEC 61000-4-2 (Contact)		±30	
Operating Temperature Range	T <sub>J</sub>	-55 to +125	°C
Storage Temperature Range	T <sub>stg</sub>	-55 to +150	°C

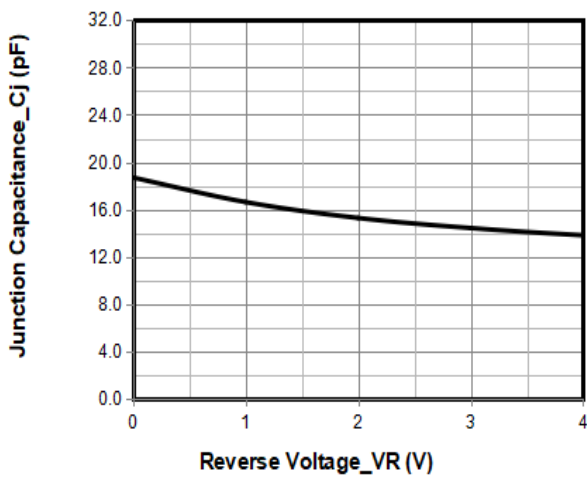
**Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise specified)**

Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V <sub>RWM</sub>			5	V	
Breakdown Voltage	V <sub>BR</sub>	6		8	V	I <sub>T</sub> = 1mA
Reverse Leakage Current	I <sub>R</sub>			0.2	μA	V <sub>RWM</sub> = 5V
Clamping Voltage	V <sub>C</sub>			8	V	I <sub>PP</sub> = 1A
Clamping Voltage	V <sub>C</sub>			13	V	I <sub>PP</sub> = 8A
Junction Capacitance	C <sub>J</sub>		18		pF	V <sub>R</sub> = 0V, f = 1MHz

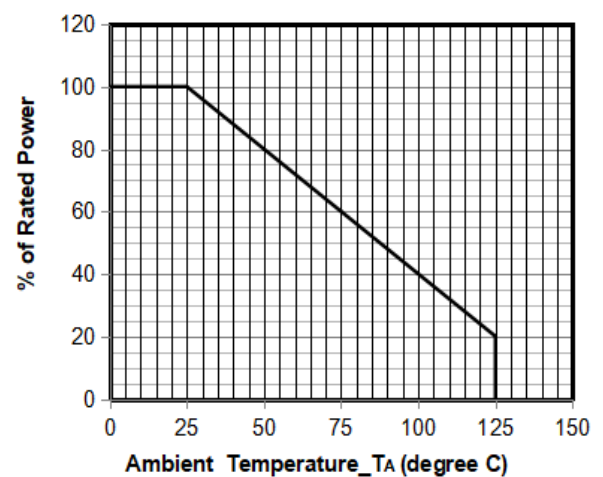
**Typical Performance Characteristics ( $T_A=25^\circ\text{C}$  unless otherwise Specified)**



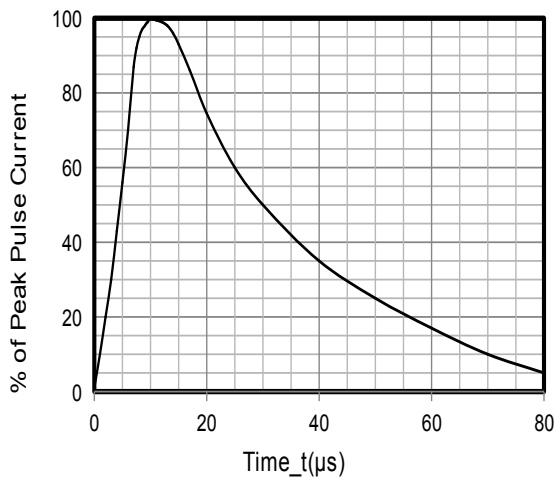
**Junction Capacitance vs. Reverse Voltage**



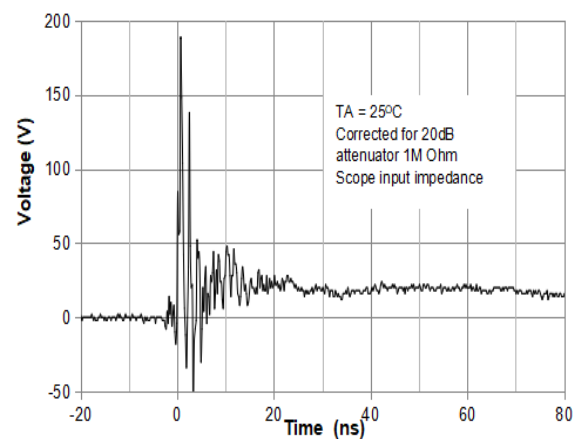
**Peak Pulse Power vs. Pulse Time**



**Clamping Voltage vs. Peak Pulse Current ( $t_p = 8/20\mu\text{s}$ )**



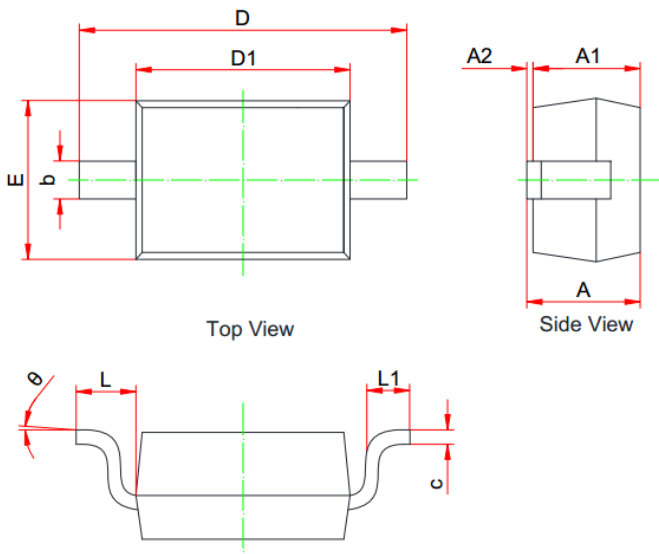
**Power Derating Curve**



**8 X 20 $\mu\text{s}$  Pulse Waveform**

**ESD Clamping Voltage  
8 kV Contact per IEC61000-4-2**

### SOD-323 Package Outline Drawing



	MILLIMETERS		
	MIN	NOM	MAX
A	0.800	--	1.100
A1	0.800	--	0.900
A2	0.000	--	0.100
b	0.250	--	0.400
c	0.080	--	0.177
D1	1.600	1.700	1.800
D	2.300	--	2.800
E	1.150	--	1.400
L	0.475REF		
L1	0.100	--	0.500
Theta	0°	--	8°

### Suggested Land Pattern



**Unit: mm**

### Contact Information

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